

### Features

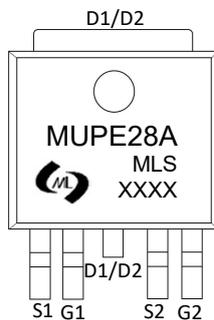
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

### Application

- Battery protection
- Load switch
- Power management

### Product Summary

V <sub>DS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX
40V	18mΩ@10V	28A
	30mΩ@4.5V	
-40V	35mΩ@-10V	-28
	55mΩ@-4.5V	

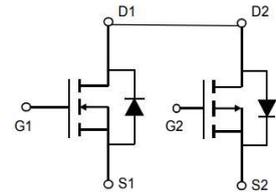


Marking and pin assignment

MUPE28A: Device code  
 XXXX: Code



TO-252-4L top view



Schematic diagram



Halogen-Free

### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	N-Channel	P-Channel	Unit
--------	-----------	-----------	-----------	------

### Common Ratings (TC=25°C Unless Otherwise Noted)

V <sub>DS</sub>	Drain-Source Breakdown Voltage	40	-40	V
V <sub>GS</sub>	Gate-Source Voltage	±20	±20	V
T <sub>J</sub>	Maximum Junction Temperature	150	150	°C
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	-55 to 150	°C
I <sub>S</sub>	Diode Continuous Forward Current	Tc=25°C 28	-28	A

### Mounted on Large Heat Sink

I <sub>DM</sub>	Pulse Drain Current Tested	Tc=25°C 120	-108	A
I <sub>D</sub>	Continuous Drain Current	Tc=25°C 28	-28	A
P <sub>D</sub>	Maximum Power Dissipation	Tc=25°C 22.7	25	W
R <sub>θJA</sub>	Thermal Resistance Junction-Ambient	60	60	°C/W

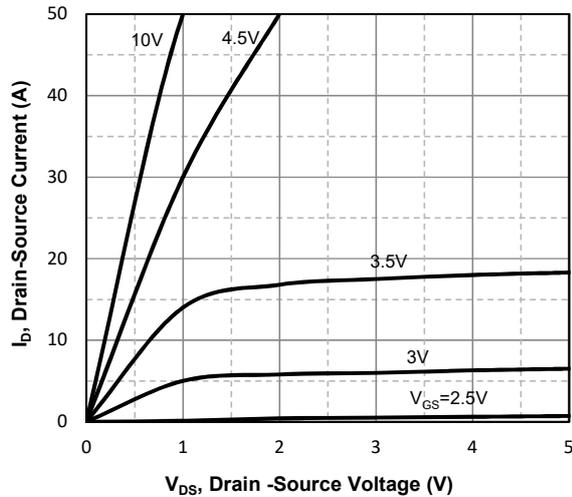
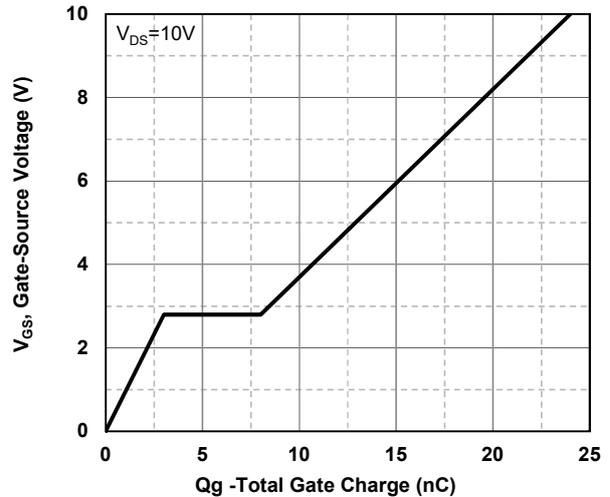
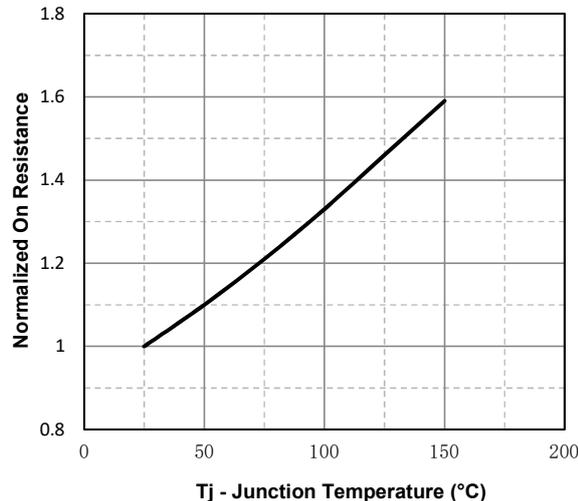
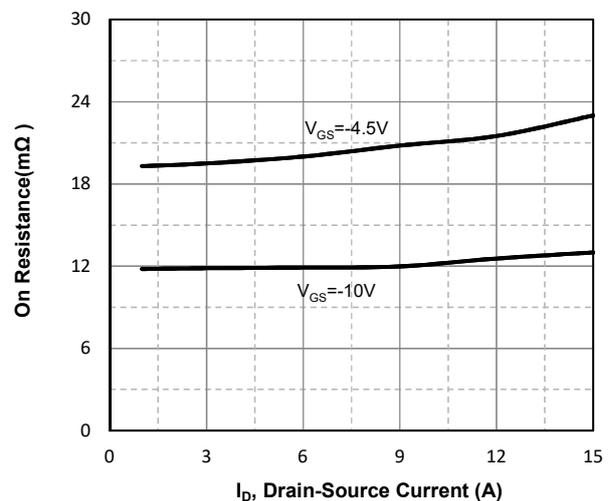
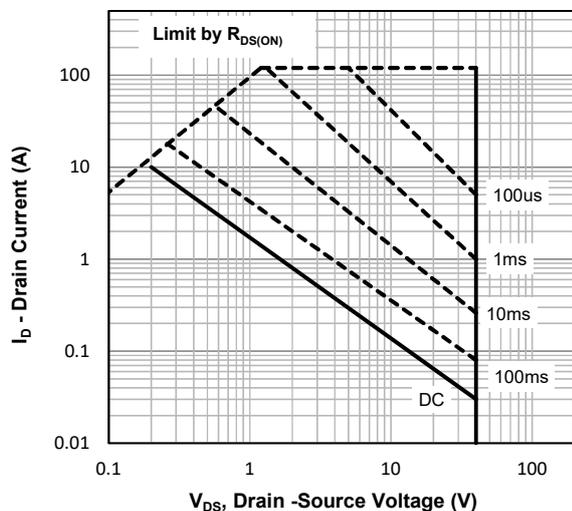
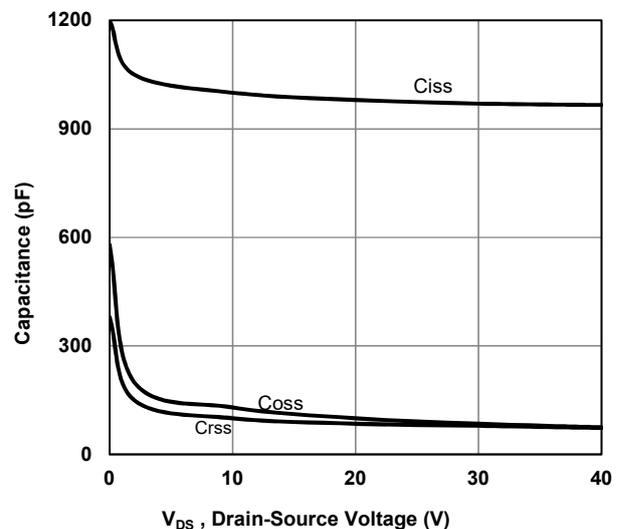
### Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MUPE28A	TO-252-4L	MUPE28A	2,500	5,000	35,000	13"reel



Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	40	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	--	--	1.0	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.7	3	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =12A	--	12	18	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A	--	20	30	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1MHz	--	965	--	pF
C <sub>OSS</sub>	Output Capacitance		--	110	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	95	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DD</sub> =20V, I <sub>D</sub> =25A, V <sub>GS</sub> =10V	--	23	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	3.5	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	5.4	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =10V, I <sub>D</sub> =10A, V <sub>GS</sub> =4.5V, R <sub>G</sub> =3Ω	--	5.5	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	15	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	25	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	11	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =10A	--	--	1.2	V

P-Ch Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-40	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-40V, V <sub>GS</sub> =0V	--	--	-1.0	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.0	-1.7	-3.0	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =-10V, I <sub>D</sub> =-8A	--	28	35	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A	--	40	55	mΩ
Dynamic Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1MHz	--	932	--	pF
C <sub>OSS</sub>	Output Capacitance		--	85	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	34	--	pF
Switching Characteristics						
Q <sub>g</sub>	Total Gate Charge	V <sub>DD</sub> =-15V, I <sub>D</sub> =-15A, V <sub>GS</sub> =-10V	--	25	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	3	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	7	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =-15V, I <sub>D</sub> =-15A, V <sub>GS</sub> =-10V, R <sub>G</sub> =2.5Ω	--	8	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	4	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	32	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	7	--	nS
Source- Drain Diode Characteristics						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =-10A	--	--	-1.2	V

**N-Channel Typical Operating Characteristics**

**Fig1. Typical Output Characteristics**

**Fig2. Typical Gate Charge Vs. Gate-Source Voltage**

**Fig3. Normalized On-Resistance Vs. Temperature**

**Fig4. On-Resistance Vs. Drain-Source Current**

**Fig5. Maximum Safe Operating Area**

**Fig6. Typical Capacitance Vs. Drain-Source Voltage**

**P-Channel Typical Operating Characteristics**

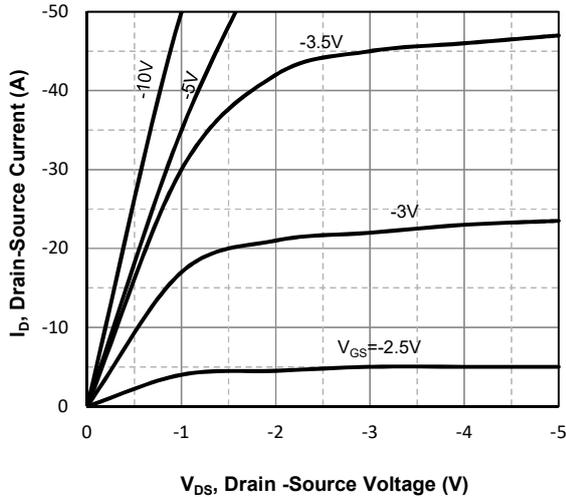


Fig7. Typical Output Characteristics

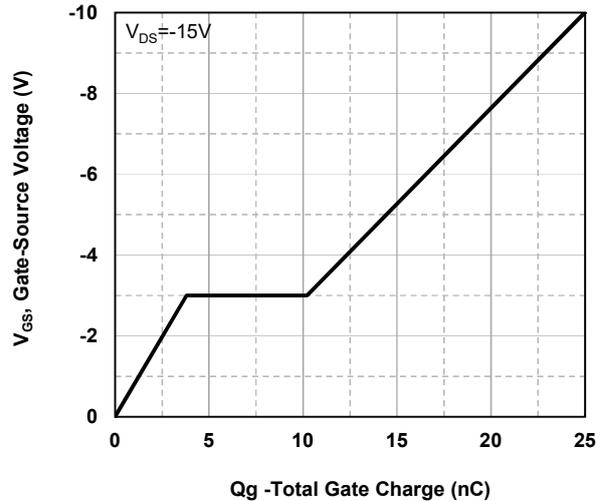


Fig8. Typical Gate Charge Vs. Gate-Source Voltage

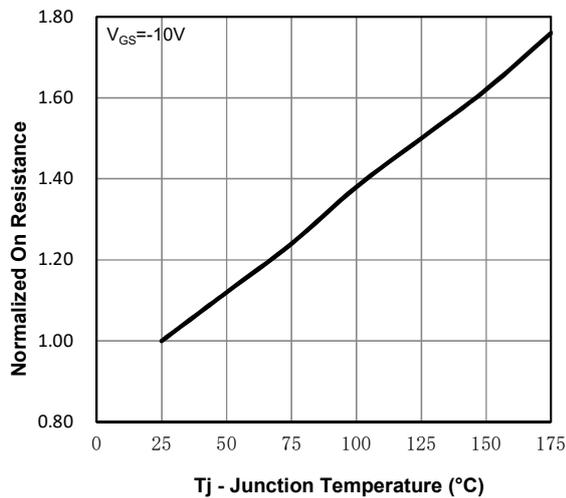


Fig9. Normalized On-Resistance Vs. Temperature

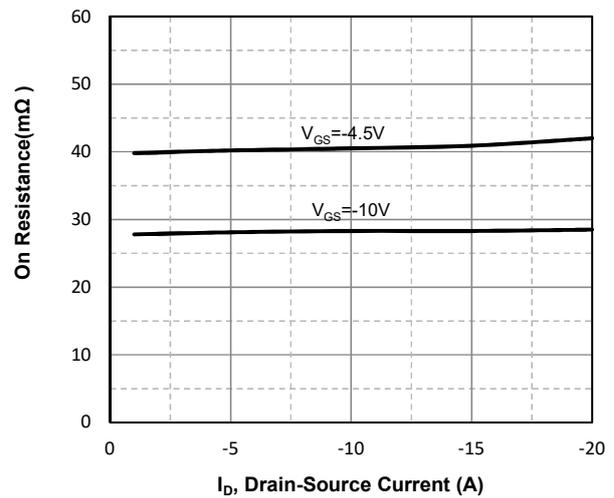


Fig10. On-Resistance Vs. Drain-Source Current

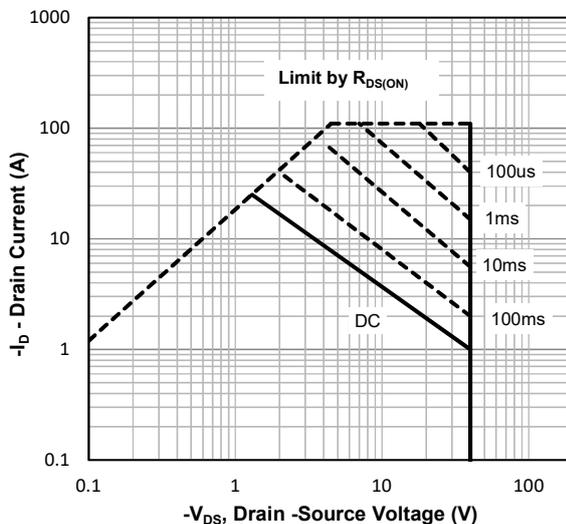


Fig11. Maximum Safe Operating Area

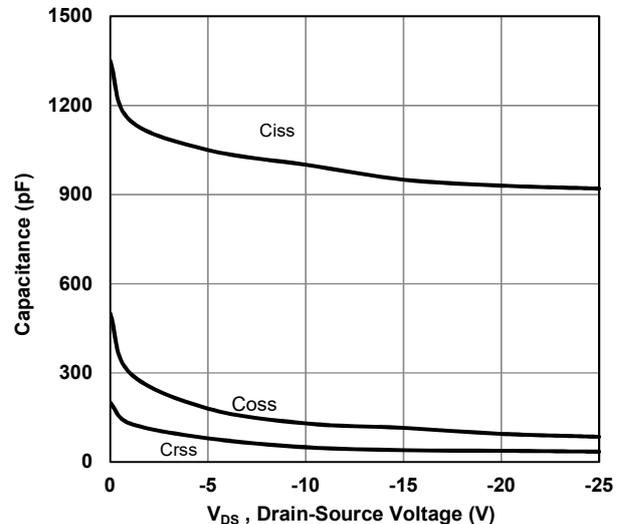
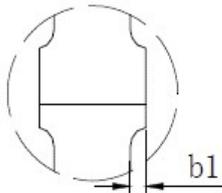
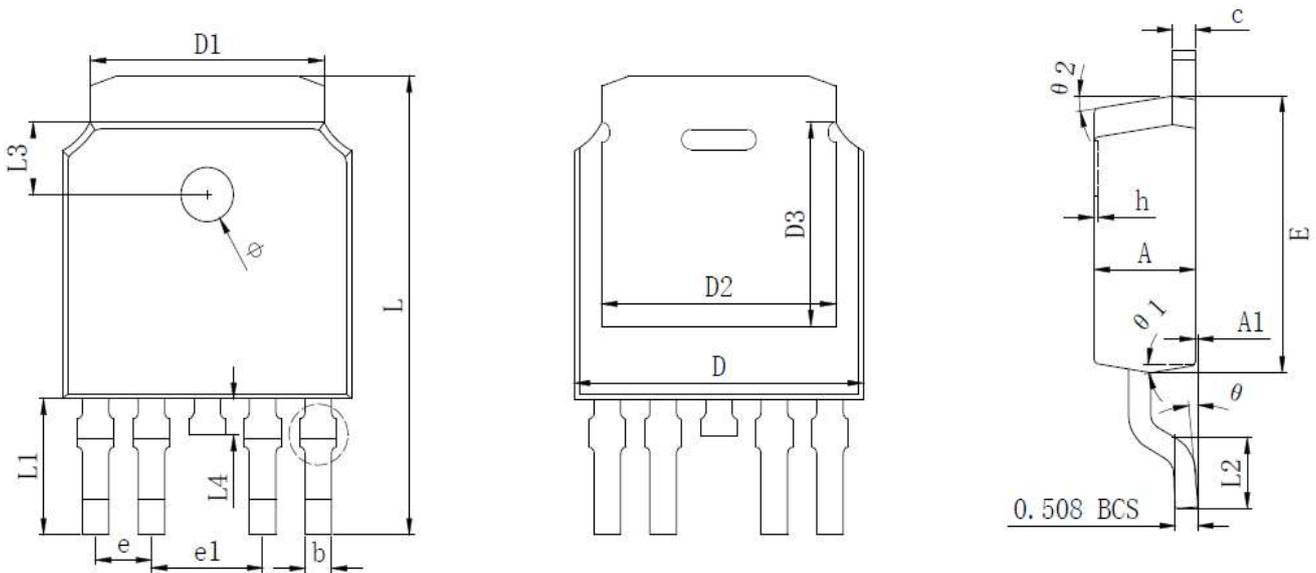


Fig12. Typical Capacitance Vs. Drain-Source Voltage

**TO-252-4L Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.550	0.650	0.022	0.026
b1	0.000	0.120	0.000	0.005
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.334(REF)		0.210(REF)	
D2	5.346(REF)		0.210(REF)	
D3	4.490(REF)		0.177(REF)	
E	6.000	6.200	0.236	0.244
e	1.270(TYP)		0.050(TYP)	
e1	2.540(TYP)		0.100(TYP)	
h	0.000	0.200	0.000	0.008
L	9.900	10.300	0.390	0.406
L1	2.988(REF)		0.117(REF)	
L2	1.400	1.700	0.055	0.067
L3	1.600(REF)		0.063(REF)	
L4	0.700	0.900	0.028	0.035
φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
θ1	9°(TYP)		9°(TYP)	
θ2	9°(TYP)		9°(TYP)	